imall

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Power MOSFET

1 Amp, 20 Volts, P-Channel TSOP-6

Features

- Ultra Low R_{DS(on)}
- Higher Efficiency Extending Battery Life
- Miniature TSOP-6 Surface Mount Package
- NV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

• Power Management in Portable and Battery–Powered Products, i.e.: Cellular and Cordless Telephones, and PCMCIA Cards

Rating	Symbol	Value	Unit	
Drain-to-Source Voltage	V _{DSS}	-20	V	
Gate-to-Source Voltage - Continuous	V _{GS}	± 8.0	V	
Thermal Resistance Junction-to-Ambient (Note 1) Total Power Dissipation @ $T_A = 25^{\circ}C$ Drain Current – Continuous @ $T_A = 25^{\circ}C$ – Pulsed Drain Current ($T_p < 10 \mu S$)	R _{θJA} P _d I _D I _{DM}	244 0.5 -1.65 -10	°C/W W A A	
Thermal Resistance Junction-to-Ambient (Note 2) Total Power Dissipation @ $T_A = 25^{\circ}C$ Drain Current – Continuous @ $T_A = 25^{\circ}C$ – Pulsed Drain Current ($T_p < 10 \ \mu$ S)	R _{θJA} Pd I _D I _{DM}	128 1.0 -2.35 -14	°C/W W A A	
Thermal Resistance Junction-to-Ambient (Note 3) Total Power Dissipation @ $T_A = 25^{\circ}C$ Drain Current – Continuous @ $T_A = 25^{\circ}C$ – Pulsed Drain Current ($T_p < 10 \ \mu S$)	R _{θJA} Pd I _D I _{DM}	62.5 2.0 -3.3 -20	°C/W W A A	
Operating and Storage Temperature Range	T _J , T _{stg}	-55 to 150	°C	
Maximum Lead Temperature for Soldering Purposes for 10 Seconds	ΤL	260	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Minimum FR-4 or G-10 PCB, operating to steady state.

- Mounted onto a 2" square FR-4 board (1 in sq, 2 oz. Cu. 0.06" thick single sided), operating to steady state.
- Mounted onto a 2" square FR-4 board (1 in sq, 2 oz. Cu. 0.06" thick single sided), t < 5.0 seconds.



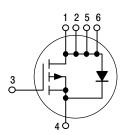
ON Semiconductor®

http://onsemi.com

1 AMPERE 20 VOLTS

 $R_{DS(on)} = 90 \text{ m}\Omega$

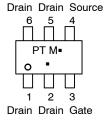




MARKING DIAGRAM & PIN ASSIGNMENT



М



PT = Specific Device Code

= Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

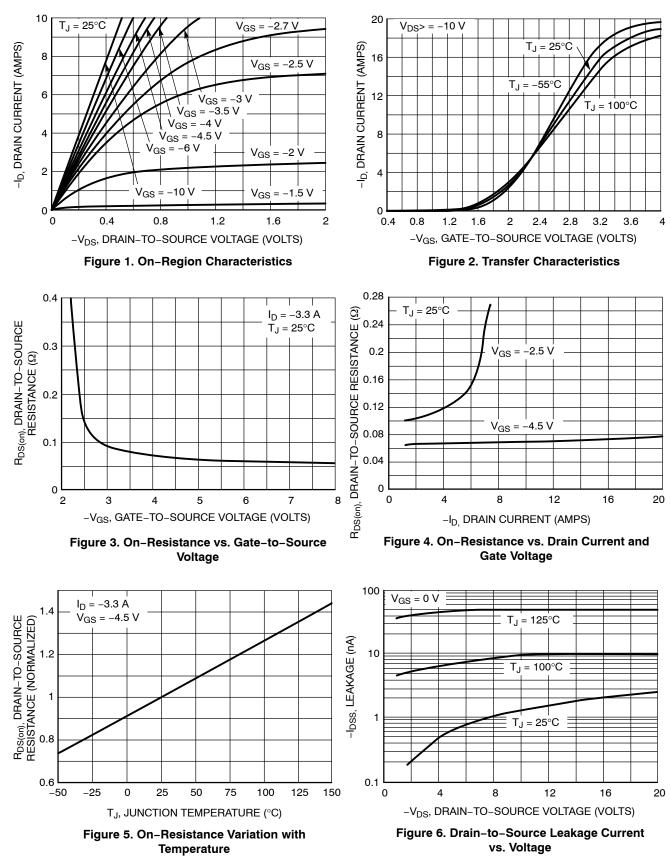
Device	Package	Shipping [†]
NTGS3441T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel
NVGS3441T1G	TSOP-6 (Pb-Free)	3000 / Tape& Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

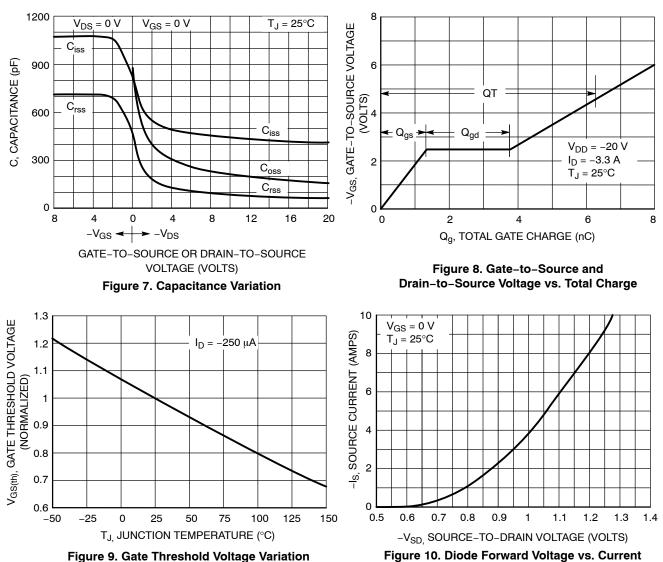
ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted) (Notes 4 & 5)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Drain–Source Breakdown Voltage (V _{GS} = 0 Vdc, I_D = -10 μ A)		V _{(BR)DSS}	-20	-	-	Vdc
Zero Gate Voltage Drain Current ($V_{GS} = 0 \text{ Vdc}, V_{DS} = -20 \text{ Vdc}, T_J = 25^{\circ}\text{C}$) ($V_{GS} = 0 \text{ Vdc}, V_{DS} = -20 \text{ Vdc}, T_J = 70^{\circ}\text{C}$)		I _{DSS}	-	- -	-1.0 -5.0	μAdc
Gate-Body Leakage Current (V _{GS} = -8.0 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	_	-100	nAdc
Gate-Body Leakage Current (V _{GS} = +8.0 Vdc, V _{DS} = 0 Vdc)		I _{GSS}	-	_	100	nAdc
ON CHARACTERISTICS						
Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = -250 \ \mu Adc$)		V _{GS(th)}	-0.45	-1.05	-1.50	Vdc
$\begin{array}{l} \mbox{Static Drain-Source On-State Resistance} \\ (V_{GS} = -4.5 \mbox{ Vdc}, \mbox{ I}_D = -3.3 \mbox{ Adc}) \\ (V_{GS} = -2.5 \mbox{ Vdc}, \mbox{ I}_D = -2.9 \mbox{ Adc}) \end{array}$		R _{DS(on)}	-	0.069 0.117	0.090 0.135	Ω
Forward Transconductance $(V_{DS} = -10 \text{ Vdc}, I_D = -3.3 \text{ Adc})$		g fs	-	6.8	_	Mhos
DYNAMIC CHARACTERISTICS						
Input Capacitance		C _{iss}	-	480	-	pF
Output Capacitance	(V _{DS} = -5.0 Vdc, V _{GS} = 0 Vdc, f = 1.0 MHz)	C _{oss}	1	265	-	pF
Reverse Transfer Capacitance		C _{rss}	1	100	-	pF
SWITCHING CHARACTERISTICS						
Turn-On Delay Time		t _{d(on)}	1	13	25	ns
Rise Time	(V _{DD} = -20 Vdc, I _D = -1.6 Adc,	t _r	1	23.5	45	ns
Turn-Off Delay Time	V_{GS} = -4.5 Vdc, R_g = 6.0 Ω)	t _{d(off)}	Ι	27	50	ns
Fall Time		t _f	1	24	45	ns
Total Gate Charge		Q _{tot}	1	6.2	14	nC
Gate-Source Charge	(V _{DS} = -10 Vdc, V _{GS} = -4.5 Vdc, I _D = -3.3 Adc)	Q _{gs}	-	1.3	-	nC
Gate-Drain Charge		Q _{gd}	I	2.5	-	nC
BODY-DRAIN DIODE RATINGS						
Diode Forward On-Voltage	$(I_{\rm S}$ = -1.6 Adc, $V_{\rm GS}$ = 0 Vdc)	V _{SD}	-	-0.88	-1.2	Vdc
Diode Forward On-Voltage	$(I_{\rm S}$ = -3.3 Adc, $V_{\rm GS}$ = 0 Vdc)	V _{SD}	I	-0.98	-	Vdc
Reverse Recovery Time	$(I_{\rm S} = -1.6 \text{ Adc}, dI_{\rm S}/dt = 100 \text{ A}/\mu\text{s})$	t _{rr}	_	30	60	ns

Indicates Pulse Test: P.W. = 300 μsec max, Duty Cycle = 2%.
 Handling precautions to protect against electrostatic discharge are mandatory.



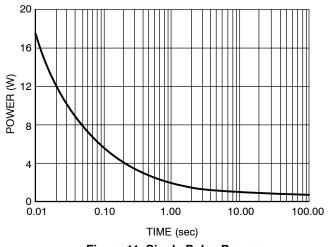
TYPICAL ELECTRICAL CHARACTERISTICS



with Temperature

TYPICAL ELECTRICAL CHARACTERISTICS

TYPICAL ELECTRICAL CHARACTERISTICS





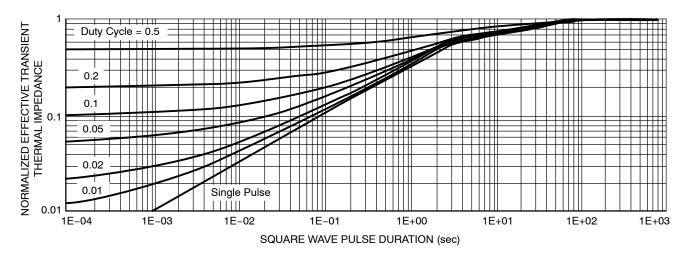
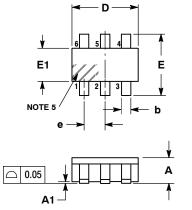
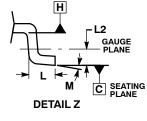


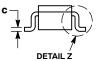
Figure 12. Normalized Thermal Transient Impedance, Junction-to-Ambient

PACKAGE DIMENSIONS

TSOP-6 CASE 318G-02 ISSUE V







NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D
- AND E1 ARE DETERMINED AT DATUM H. 5. PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

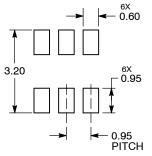
	MILLIMETERS		
DIM	MIN	NOM	MAX
Α	0.90	1.00	1.10
A1	0.01	0.06	0.10
b	0.25	0.38	0.50
с	0.10	0.18	0.26
D	2.90	3.00	3.10
E	2.50	2.75	3.00
E1	1.30	1.50	1.70
е	0.85	0.95	1.05
L	0.20	0.40	0.60
L2	0.25 BSC		
M	0°	-	10°



STYLE 1: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SOURCE

5. DRAIN 6. DRAIN

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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